

Caractérisation et Qualification d'un Dosimètre Personnel Électronique Neutrons


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Contexte: dosimétrie opérationnelle N

L'existant (IPHC): chips AlphaRad2 et 3

Ce qui reste à faire:

- a) système complet
- b) tests en sources + simulations

 Qualification

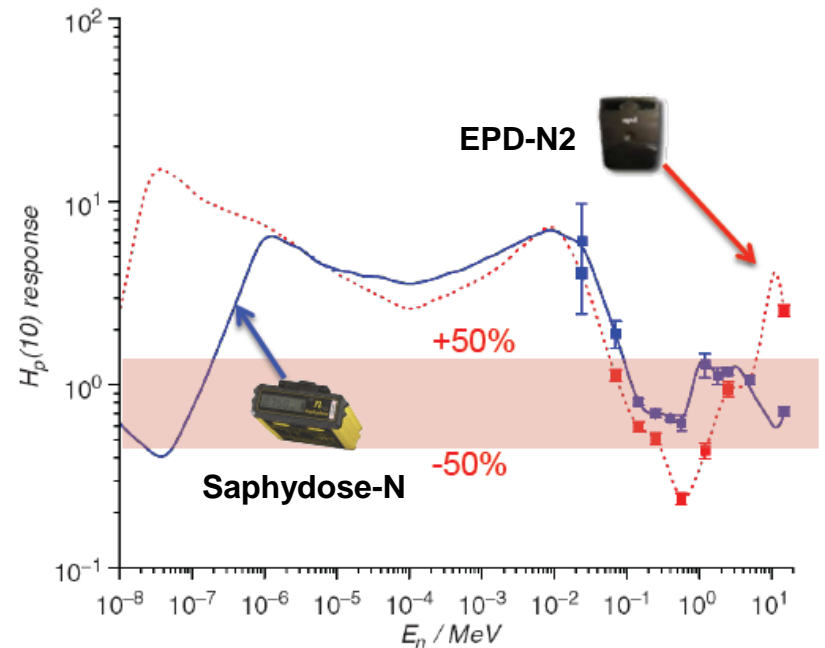
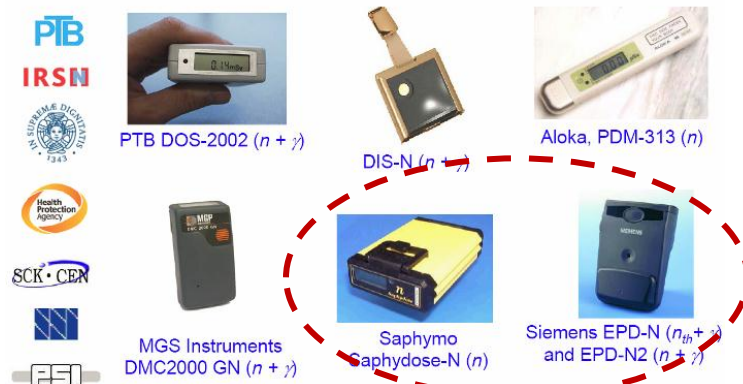
- International norm IEC 1323, 1995
 - Neutron electronic dosimeters mandatory

- EVIDOS (Evaluation of Individual DOSimetry) EU survey: 2001-2005

==> 2 neutron dosimeters:

—Saphymo-IRSN: Saphydose-N (ISO)

EVIDOS Electronic Personal Dosimeters

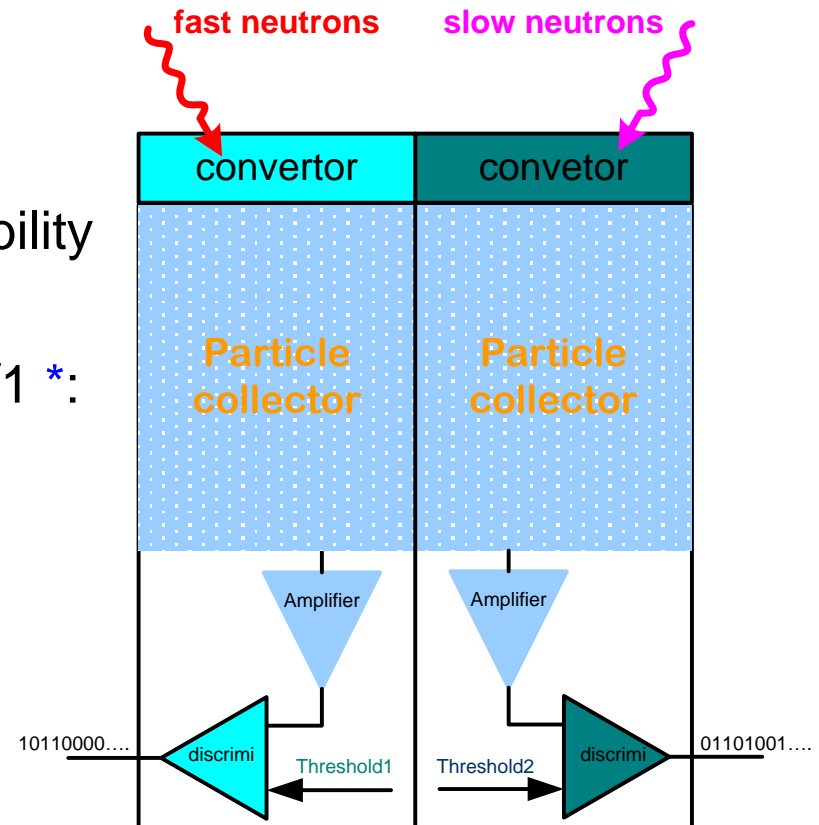


[1] M. Reginatto et al, Rad. Prot. Dos. 125 (2007) 285-288

Electronic Personal Dosimetry

Requirements:

- Real-time + high sensitivity
(→ alarm @ 20 mSv..)
- Low P consumption → 24h portability
- Cheap (→ 65000 workers in UE)
- Smartness (n/γ discrim. OK @ 1/1 *:
what about 1/10 or 1/100..?)
- Growing demand:
 - a) UE recommandations
 - b) **dismantling** is just starting..
 - c) cyclotrons everywhere !

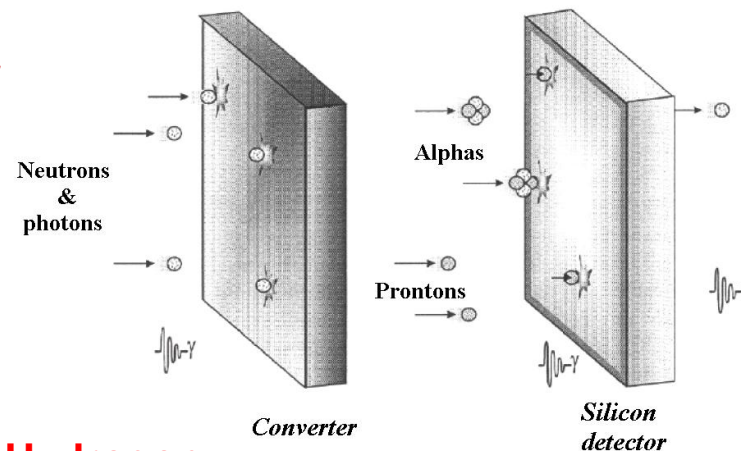


** Thèse Ying Zhang (19/09/2012)*

□ Detection of charged particles → neutron converters needed !

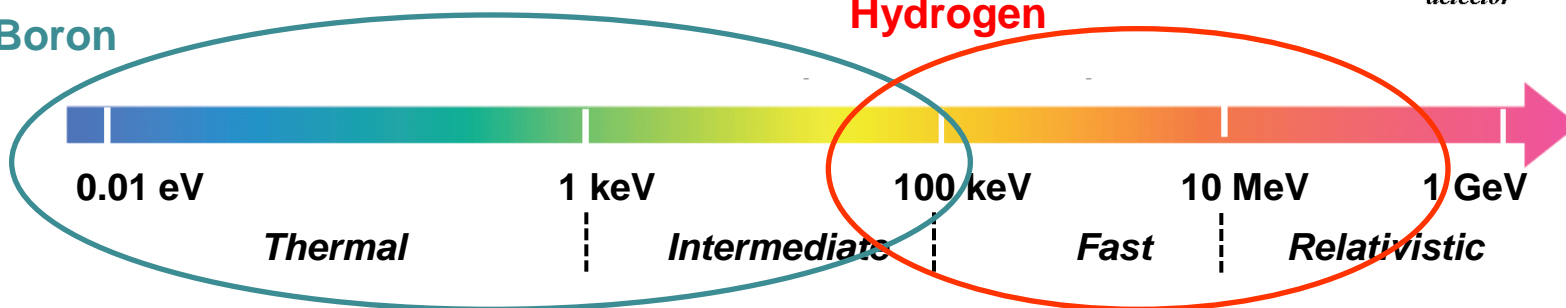
➤ Thermal neutrons: $n + {}^{10}\text{B} \rightarrow {}^7\text{Li} + \alpha$
Boron converter

➤ Fast neutrons: $n + \text{H} \rightarrow n + \text{p}$
(CH_2)_n converter



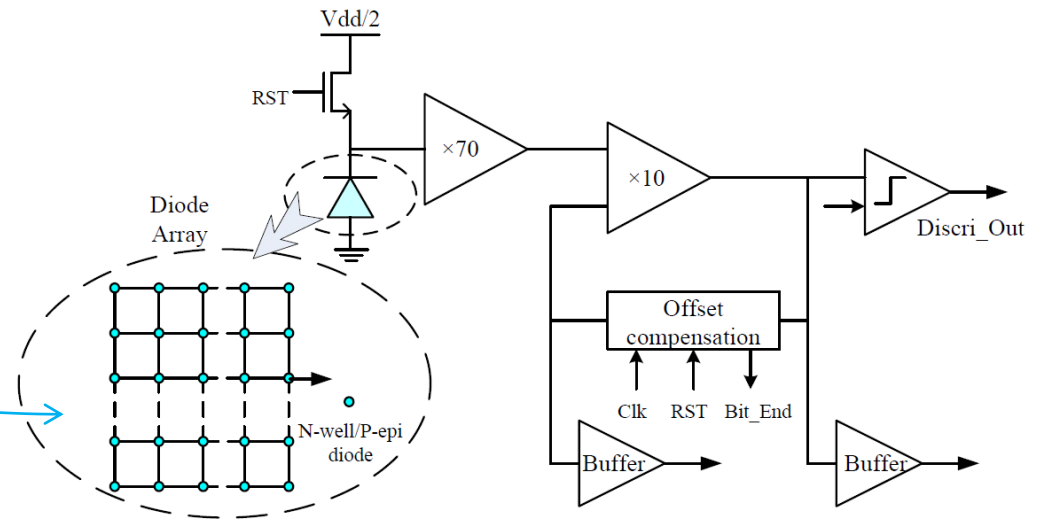
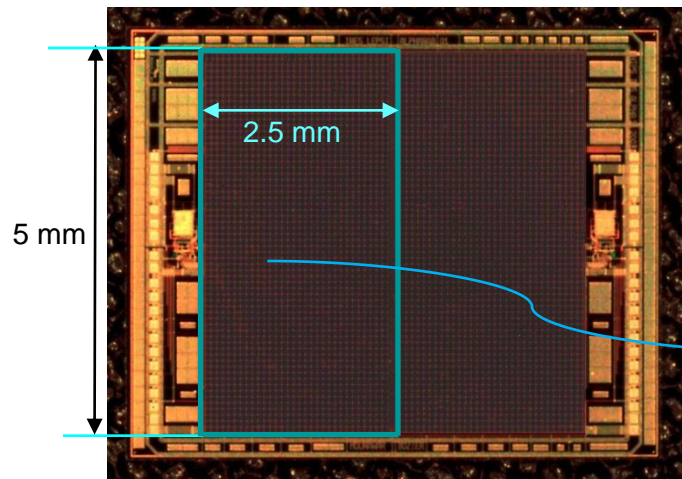
Boron

Hydrogen



□ Wide energy range → two converters of different nature

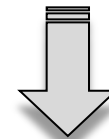
AlphaRad1: dedicated chip for direct α detection (2006)



- 32 × 64 diodes in parallel with a single output
- High detection efficiency for 5 MeV alpha particles (~100%)
- ➔ ➔ **Fast counting on a large area achieved without pixellization**

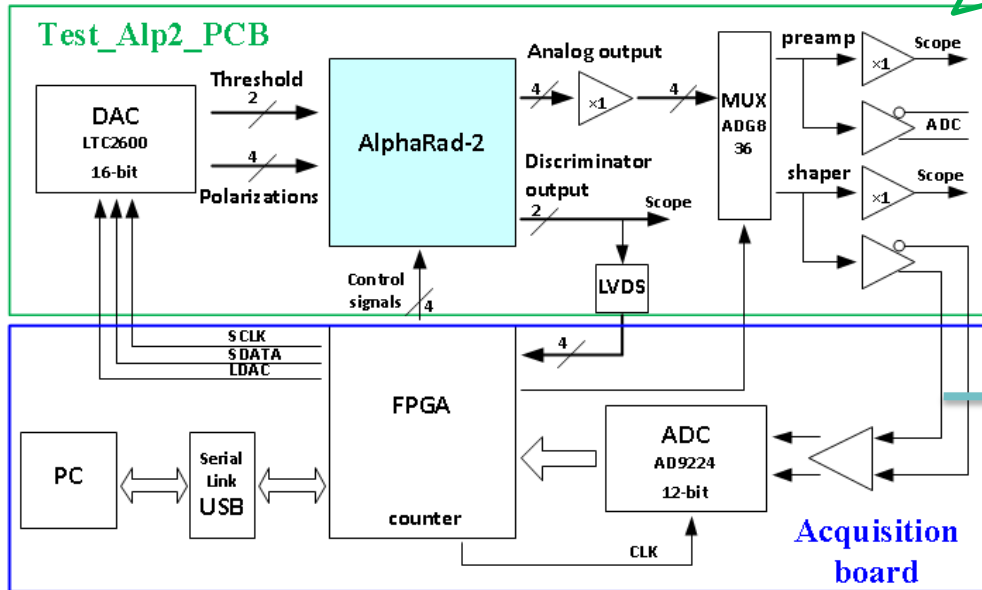
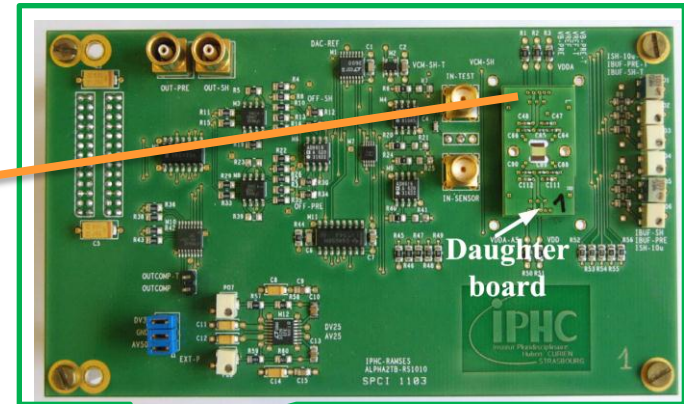
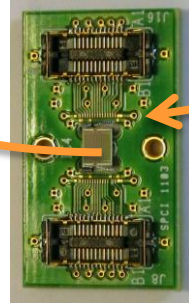
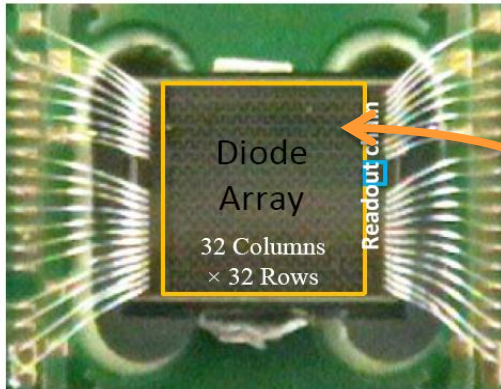
Drawbacks

- Equivalent noise charge (ENC) ~14 000 e^-
→ too high for fast neutrons (threshold 50 000 e^-)
- Power consumption ~10 mW
→ needs to be reduced !!



New chip dedicated to a neutron dosimeter₆

AlphaRad2 (2012)



Test options:

- Oscilloscope
- ADC outputs

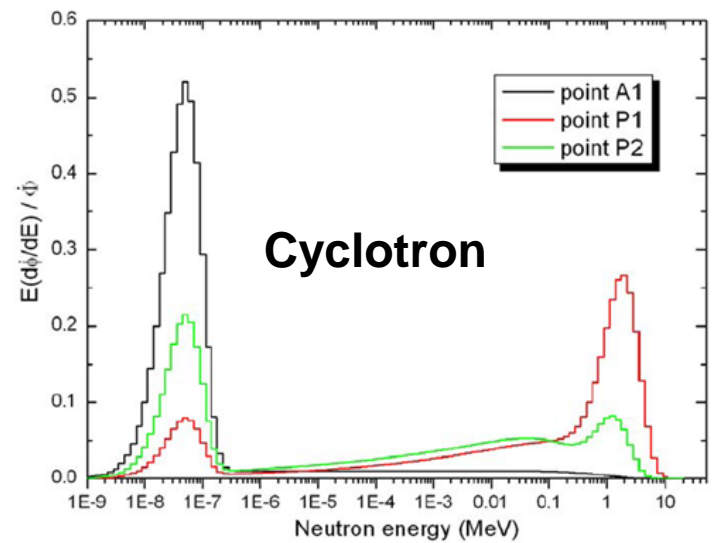
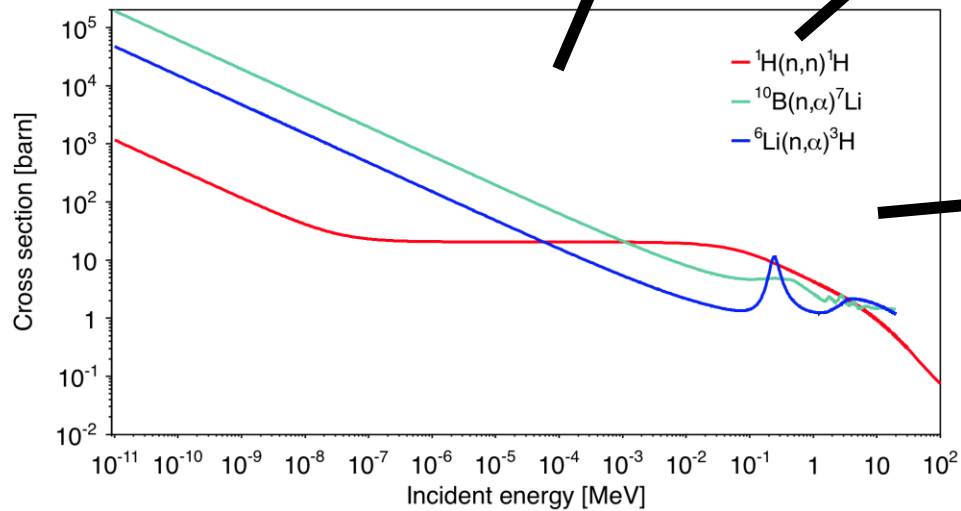
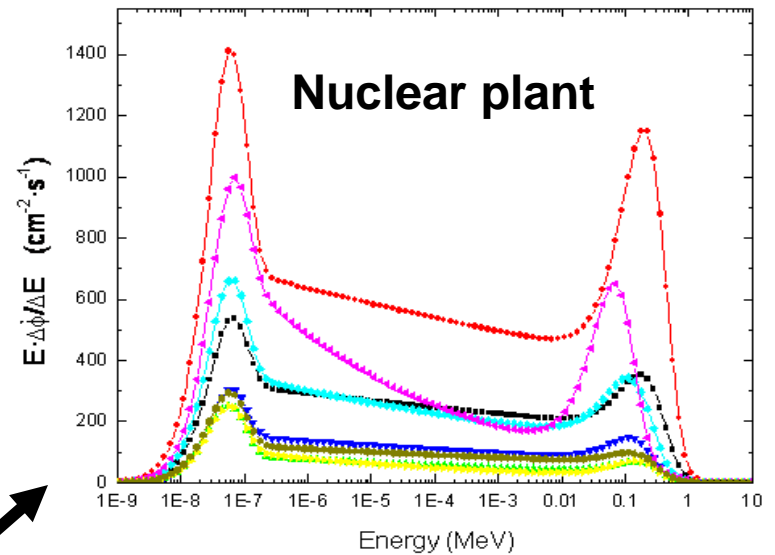
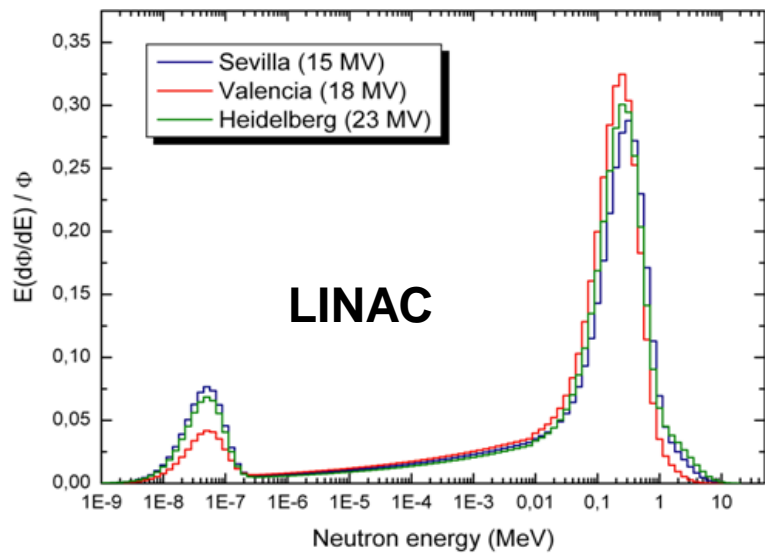
Digitalize analog signals (output of CSA/shaper)

Experimental tests (LMDN Cadarache)

Van Gogh: AmBe source , $A = 370 \text{ GBq}$
Fast n + γ 4.438 MeV, fluences well defined(4%)

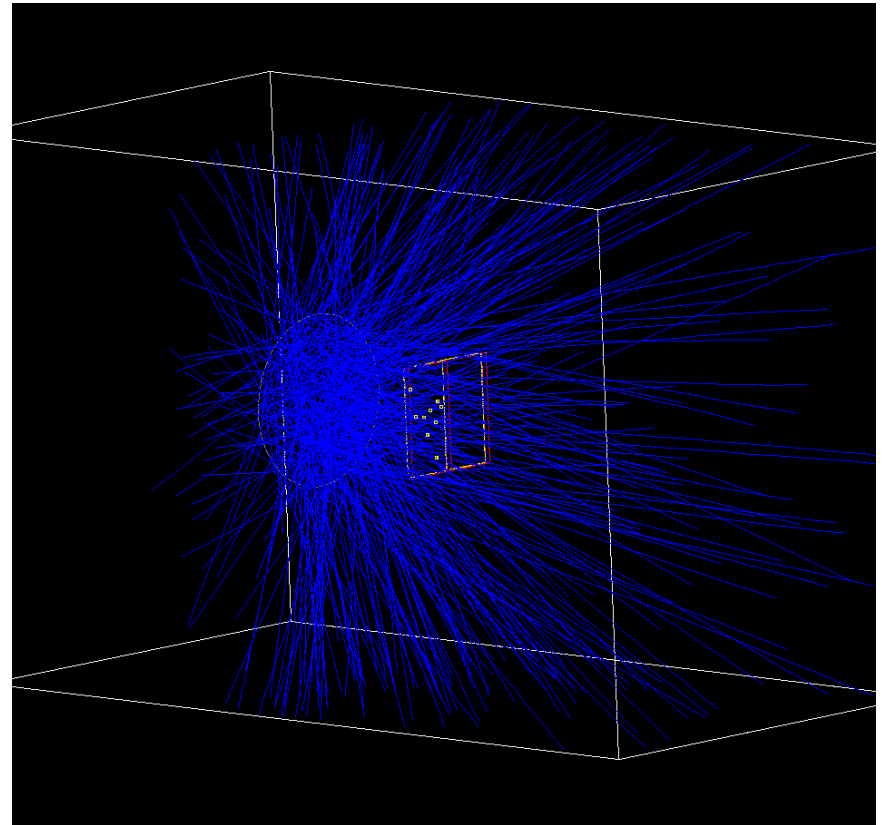
AMANDE facility : mono-E neutrons
(3 keV-20 MeV)





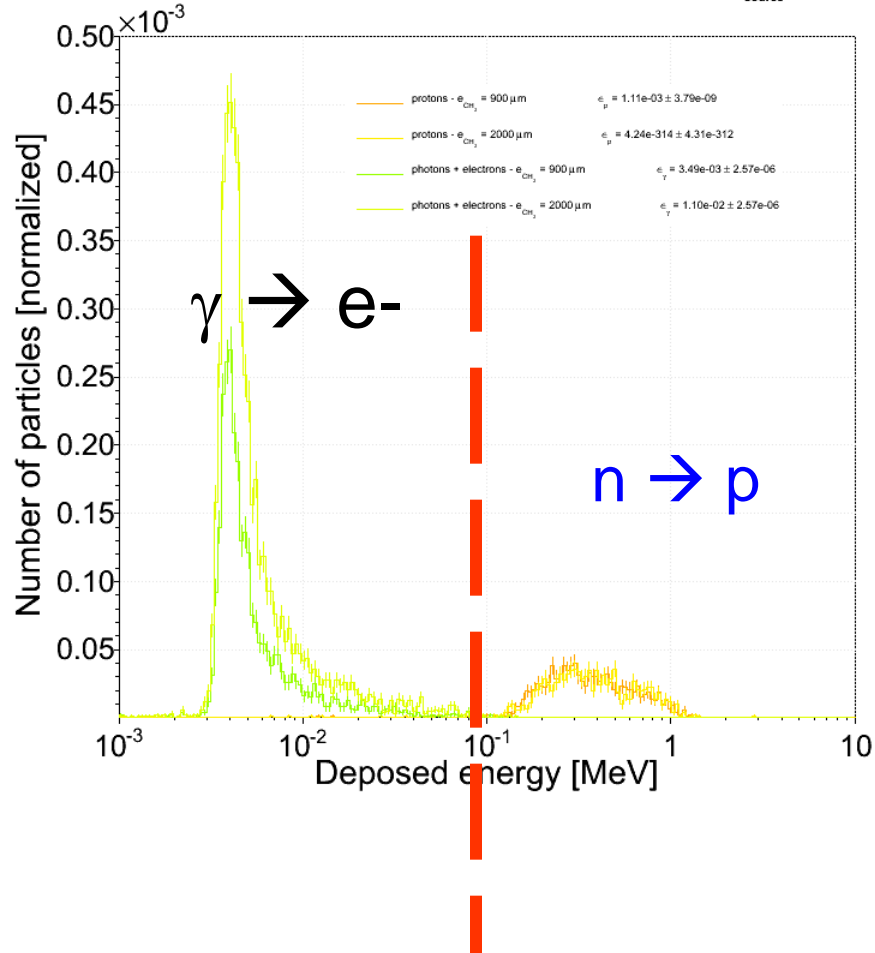
Simulation

- GEANT IV
- MCNPX

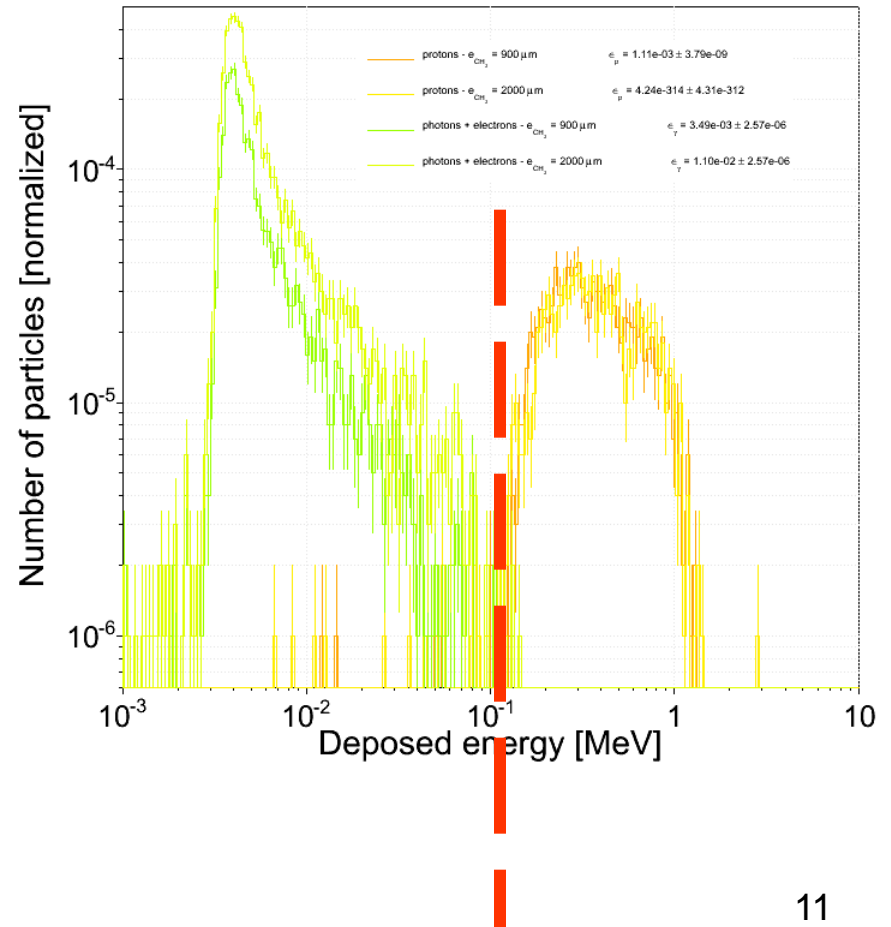


Discrimination n/γ : Simulations...

Deposited energy in CMOS sensor calculated by MCNPX 2.6f simulation [nps = 1e6, d_{source} = 15 cm]



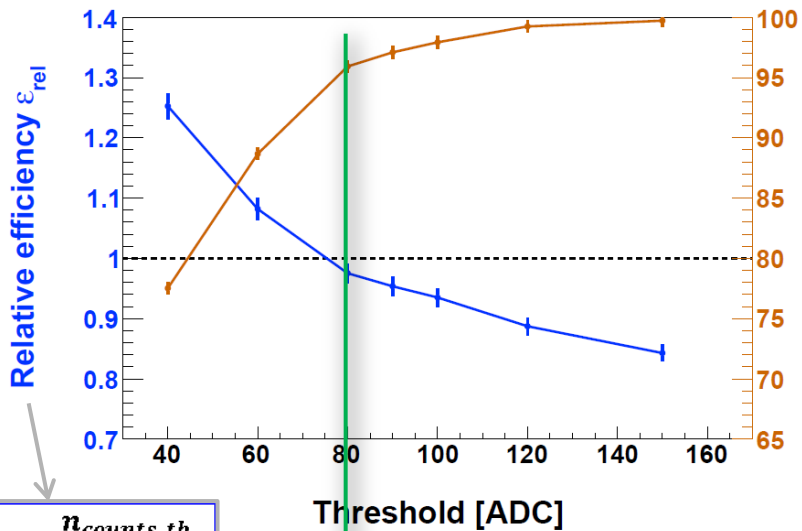
Deposited energy in CMOS sensor calculated by MCNPX 2.6f simulation [nps = 1e6, d_{source} = 15 cm]



...and real life !

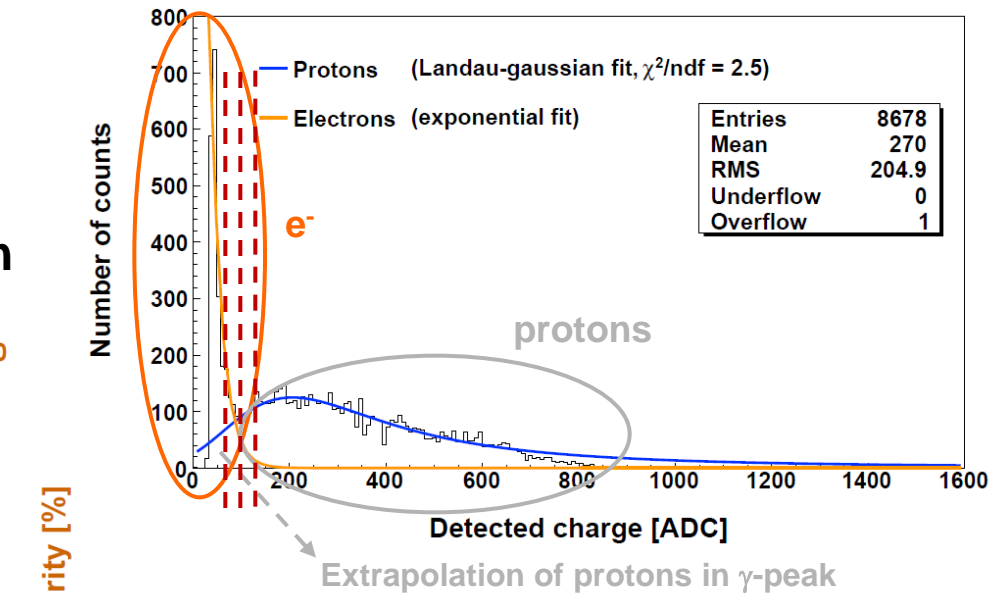
- AmBe source, d = 20 cm
- 310-min exposure
- 500 μm-thick (CH₂)_n converter

→ Threshold for n/γ discrimination



$$\epsilon_{rel} = \frac{n_{counts_th}}{n_{protons}}$$

Q > 80 ADC → High eff. + good purity



$$p = 1 - \frac{n_{electrons}}{n_{counts_th}}$$


80 ADC

$$\epsilon_{int} = \frac{n_{det.protons}}{n_{neutrons}}$$

$$\epsilon_{int} = (7.24 \pm 0.32^*) \times 10^{-4}$$

*statistical & source uncertainties

Programme de travail

- Système complet portatif / autonome (PCB: 4 chips + 2 conv.) prêt au printemps 2013
- Réponse sur raies mono-E
- Réponse sur spectres étendus
- Réponse angulaire
- Influence n lents diffusés }  *Fantômes anthropom.*
- Discrimin / γ dans combinaisons artificielles de sources mixtes (1/10, 1/100, 1/1000)
- Influence T°; radhardness; blindage EM, ...